

General Description

The CS8902A is a PWM high-efficiency low-cost LED driver control IC which provides an efficient solution for off-line high-brightness LED lamps from rectified line voltage ranging from 85VAC up to 305VAC. The CS8902A control an external N-channel power MOSFET at a fixed switching frequency up to 600kHz. The switching frequency is determined by an external single resistor.

The CS8902A topology creates a constant current through the LEDs delivering a more uniform light output. The output current is programmed by one external resistor and is ultimately determined by the external N-channel power MOSFET chosen and therefore allows LEDs current between a few mA and up to more than 1A.

The CS8902A supports a several kHz PWM dimming input and a 0 to 250mV linear dimming input. The CS8902A provides protection functions including input Under Voltage Lockout (UVLO), output Short Circuit Protection (SCP), Open Loop Protection (OLP) and Over Temperature Protection (OTP). The CS8902A is available in a standard 8-lead SOP plastic (SOP-8) and the thermally enhanced PSOP-8 packages.

Features

High efficiency up to 90% ± 4% Current sensing voltage variation Universal rectified 85VAc to 305VAc input range DC input voltage range from 9V to 500V Application from a few mA up to more than 1A Open loop peak current controller Support PWM and linear dimming Input under voltage lockout Over temperature protection Output short circuit protection Output open loop protection Drive an external low-cost N-channel MOSFET Available in SOP-8 and PSOP-8 packages RoHS compliant and halogen free

Applications

Off-line LEDs lamp Back lighting of flat panel display Signage and decorative LEDs lighting General purpose constant current source Middle voltage (24V/36V) stage LEDs lighting Low voltage automotive (12V/24V) LEDs lighting Charger, Stage LEDs lighting

Pin Configurations



Simplified Application Circuit

Order Information







Functional Pin Description

D : N	Pin No.		Dia Francisca		
Pin Name	SOP-8	PSOP-8	Pin Function		
VIN	1	1	DC input voltage. This pin is the input of a 9V to 500V high voltage linear regulator.		
CS	2	2	LEDs current sensing input. The typical current sensing threshold voltage (Vcs) is 250mV between the CS and GND pins.		
GND	3	3	Ground of the chip.		
GATE	4	4	This pin is the output gate driver for an external N-channel power MOSFET.		
PWM_D	5	5	This pin can be used for LEDs short circuit protection with some external circuitry. Low frequency PWM dimming pin, also enable input. Internal $100k\Omega$ pull-down resistor to GND pin.		
VDD	6	6	Regulated supply voltage output. Can supply up to 1mA for external circuitry. A sufficient storage low ESR capacitor (\sim 10µF) is used to provide storage when the rectified AC input is near the zero crossing.		
LD	7	7	Linear dimming control input pin. Apply a voltage less than V_{CS} ($V_{LD} < V_{CS}$) to dim the LEDs output current.		
ROSC	8	8	This pin sets the oscillator frequency. A external oscillating resistor (Rosc) connected between this pin to GND pin sets the oscillator PWM frequency. The controller can be switched into constant off-time (PFM) mode by connecting the external oscillating resistor between ROSC pin and the gate of the external power MOSFET.		
EP	N/A	9	Exposed pad (Bottom of package). This pad must be soldered to a large PCB and connected to GND directly for maximum thermal dissipation.		

Function Block Diagram





CHIPLUS

Absolute Maximum Ratings (Note 1)	
VIN input pin DC supply voltage, V_{IN}	−0.5V to 525V
CS input pin voltage, Vcs	0.3V to (VDD + 0.3V)
PWM_D input pin voltage, VPWM_D	0.3V to (V _{DD} + 0.3V)
LD input pin voltage, VLD	0.3V to (V _{DD} + 0.3V)
GATE output pin voltage, Vg	0.3V to (V _{DD} + 0.3V)
Power dissipation, $P_D @ T_A = 25^{\circ}C$ (Note 2)	
SOP-8	1.29W
PSOP-8 (Exposed pad)	1.67W
Package thermal resistance (Note 3)	
SOP-8, θ _{JA}	77.6°C/W
SOP-8, θJC	10.8°C/W
PSOP-8 (Exposed pad), θ _{JA}	60°C/W
PSOP-8 (Exposed pad), θ _{JC}	2°C/W
Junction temperature, TJ	150°C
Lead temperature (Soldering, 10 sec.)	260°C
Storage temperature range	−65°C to 150°C
ESD (Electrostatic Discharge) susceptibility (Note 4)	
HBM (Human Body Model with VIN pin)	1.5kV
MM (Machine Model with VIN pin)	200V
Recommended Operating Conditions (Note 5)	
Supply DC input voltage range, VIN	9V to 500V
LD input pin voltage range, VLD	0V to V _{DD}
PWM_D input pin voltage range, VPWM_D	0V to VDD
Junction temperature range, TJ	−40°C to 125°C
Ambient temperature range for SOP-8 package (Note 6), TA	
Ambient temperature range for PSOP-8 package (Note 6), TAP	
(1) Exceeding these ratings may damage the device	
 (1). Exceeding these ratings may defined use the device. (2) The maximum allowable power dissipation is a function of the maximum insertion temperate 	ure Turny the junction to emplore thermal resistance
(z). The maximum allowable power dissipation is a function of the maximum junction temperat	
Us, and the ambient temperature 1A. Exceeding the maximum allowable power dissipation will	i cause excessive die temperature, and the controller

will go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.

(3). Measured on JEDEC 51-7 thermal measurement standard, 4-layer PCB. The PCB dimension is 114.3 x 76.2 x 1.6 mm₃.

(4). Semiconductor devices are ESD sensitive. Handling precaution is recommended.

(5). The device function is not guaranteed outside of the recommended operating conditions.

(6). Maximum ambient temperature range is limited by allowable power dissipation. The exposed pad package PSOP-8 with its lower package thermal resistance allows the variants using this package to extend the allowable maximum ambient temperature range.



Electrical Characteristics

(T_A = 25°C, unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Тур	Мах	Unit		
DC Input								
DC input supply voltage range	VIN	DC input voltage	9		500	V		
Quiescent current at operation mode	2	VIN = 9V to 500V, PWM_D pin		0.7	1.0			
Quescent current at operation mode	Q	connect to VDD pin		0.7	1.0	ШA		
		$V_{IN} = 9V$ to 500V, PWM_D pin			0.7	mA		
Quiescent current at shutdown mode	ISHDN	connect to GND pin, $T_A = -40^{\circ}C$ to		0.4				
		85°C						
Internal Regulator								
Internally regulated output voltage	חחע	$V_{IN} = 9V$ to 500V, $I_{DD_EXT} = 0mA$,	7.0	7.5	8.0	V		
Internally regulated output voltage	VUU	GATE pin is open	7.0					
VDD under voltage lockout threshold	VUVLO	Rising VIN	6.1	6.7	7.3	V		
VDD under voltage lockout hysteresis	ΔVUVLO	Falling V _{IN}		0.5		V		
		$V_{PWM_D} = V_{DD}$, $I_{DD_EXT} = 0mA$ to 1mA,			100	mV		
VDD load regulation	ΔVDD	1nF at GATE pin, Rosc = $226k\Omega$						
		connect to GND pin						
		When an external voltage is applied			13.5	V		
Maximum vbb voltage	VDD_IVIAA	to VDD pin			13.5	v		
VDD current available for external		1/m = 91/10 = 1001/1001/1001/1001/1001/1001/100			1	mA		
circuitry (Note 7)								
Peak Current Sensing Mode		-		-				
Current sensing pull-in threshold	VCS	$V_{101} = 9V_1$ to 500V/ $T_0 = -40^{\circ}$ C to 85°C	240	250	260	m\/		
voltage	VC3		240	230	200	111V		
Current sense blanking interval	tLEB	$V_{CS} = 0.5V, V_{LD} = V_{PWM_D} = V_{DD}$	150	215	280	ns		
Delay time from CS trip to GATE low	۲D	$V_{IN} = 12V$, $V_{PWM_D} = V_{DD}$, $V_{LD} =$			300	ns		
	(D	0.15V, $V_{CS} = 0V$ to 0.22V after tLEB						
Oscillator								
	fOSC1	$Rosc = 1M\Omega$ connect to GND pin	20	25	30	kHz		
Oscillator frequency	fOSC2	$Rosc = 226k\Omega$ connect to GND pin	80	100	120	kHz		
	fOSC3	R_{OSC} = 19.8k Ω connect to GND pin	480	600	720	kHz		
Dimming								
Maximum appillating DWM duty cycle		fpwm_HF = 25kHz, at GATE pin, CS			100	%		
		pin connect to GND pin						
PWM_D pin enable threshold high	VEN_HI	VIN = 9V to 500V	2.4			V		
PWM_D pin disable threshold low	VEN_LO	VIN = 9V to 500V			1.0	V		
PWM_D pin pull-down resistance	RPWM_D	VPWM_D = 5V	50	100	150	kΩ		
LD pin dimming voltage range	VLD	VIN = 9V to 500V	0		250	mV		



Electrical Characteristics (Continue)

(T_A = 25°C, unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit		
GATE Pin Driving Output								
GATE pin high output voltage	VG_HI	$V_{IN} = 0V, V_{DD} = 7.5V, I_G = 10mA$	7.4		7.5	V		
GATE pin low output voltage	VG_LO	$V_{IN} = 0V, V_{DD} = 7.5V, I_G = -10mA$	0		0.1	V		
GATE pin output rise time	tR	Vpp = 7.5V, 1nF at GATE pin		15	20	ns		
GATE pin output fall time	tF	V _{DD} = 7.5V, 1nF at GATE pin		20	30	ns		
Protections								
PWM_D pin short circuit protection	Vpwm_d_th	Refer to Figure 5 on page 11		1.3		V		
threshold voltage								
Thermal shutdown threshold (Note 8)	TSD			150		°C		
Thermal shutdown hysteresis (Note 8)	ΔTSD			30		°C		

Notes :

(7). Also limited by package power dissipation limit, whichever is lower.

(8). Guaranteed by design.



Typical Application Circuit



Figure 1. Typical Application Circuit without PFC

Table 1. Recommend Component Selection

(For AC input voltage from 85VAc to 264VAc)

VLED (V)	ILED (mA)	F1 (A/V)	NTC	BR1	CIN (µF/V)	CC (µF/V)	CDD (µF/V)
24	350	2/250	SCK052	B6S	22/400	0.01/400	10/25
C ουτ (μ F /V)	L1 (mH)	D1	Q1 (A/V)	ROSC (kΩ)	RCS (Ω)	RST (kΩ)	ROLP (MΩ)
4.7/400	4.5	ES1J	4/600	510	0.615 (Note 9)	24	1

Note :

(9). Considering power consumption, use one 1.6 Ω resistor and two 2.0 Ω resistors with 1206 package in parallel for LED current sensing resistor (Rcs).



Typical Operating Characteristics



Variation of Current Sensing Pull-in Threshold Voltage ($\Delta V_{CS} / V_{CS}$) versus Ambient Temperature (T_A), V_{IN} = Parameter



Power Input (PIN) versus AC Input Voltage (VAC), VLED = 24V, ILED = 350mA



Efficiency versus AC Input Voltage (VAC), VLED / ILED

= Parameter



Quiescent Current at Shutdown Mode (ISHDN) versus Ambient Temperature (TA), VIN = Parameter



Output Current Variation (Δ ILED/ILED) versus AC Input Voltage (VAC), VLED = 24V, ILED = 350mA



Power Factor versus AC Input Voltage (VAC), VLED = 24V, ILED = 350mA with Passive PFC (Refer to Figure 6)



Typical Operating Characteristics (Continued)



Waveform of Soft Start, VLED = 24V, ILED = 250mA, R1 = 6k , R2 = 178k , CDD = 10 μ F, CLD = 1 μ F (Refer to Figure 2)



Waveform of Re-start at Output Short Circuit Protection, VLED = 24V, ILED = 350mA (Refer to Figure 5)



Waveform of Output Short Circuit Protection, VLED = 24V, ILED = 350mA (Refer to Figure 5)

Application Information General Description

The CS8902A is very versatile and is capable of operating in isolated or non-isolated topologies. It can also be made to operate in continuous as well as discontinuous conduction mode. The CS8902A contains a high voltage linear regulator (see Function Block Diagram on page 2) the output of the regulator provides a power rail to the internal circuitry including the gate driver. A UVLO on the output of the regulator prevents incorrect operation at low input voltage to the VIN pin.

In a non-isolated buck LEDs driver when the GATE pin goes high, it results in the external power MOSFET (Q1) is turned on causing current to flow through the LEDs, inductor (L1) and current sensing resistor (Rcs). When the voltage across Rcs exceeds the current sensing threshold voltage (Vcs) of the controller, the external power MOSFET is turned off. The stored energy in the inductor causes the current to continue to flow through the LEDs via diode (D1). The CS8902A linear regulator provides all power to the rest of the IC including GATE drive this removes the need for large high power start-up resistors. This means that operate correctly it requires around 0.7mA from the high voltage power rail. The linear regulator can also be used to supply up to 1mA to external circuits.

The CS8902A operates and regulates by limiting the peak current of the external power MOSFET; the peak current sensing threshold voltage is nominally set at 250mV. The same basic operation is true for isolated topologies; however in these the energy stored in the transformer delivers energy to LEDs during the off-cycle of the external power MOSFET.

Setting the LEDs Current

In the non-isolated buck converter topology as Figure 1 on page 6, the average LEDs current is not the peak current divided by 2 - however, there is a certain error due to the difference between the peak and the average current in the inductor. The following equation accounts for this error :

 $Rcs = \frac{0.25}{\text{ILED} + [0.5 \text{ X} (\text{ILED X 0.3})]}$

Assume the ripple current is selected to be 30% of the nominal LEDs current. ILED unit is Ampere.

Soft Start

Referring to the detail circuit in Figure 2. The LD pin provides a simple cost effective solution to soft start; by connecting a capacitor (CLD) to the LD pin down to ground at initial power up the LD pin will be held low causing the current sensing threshold voltage to be low. As the capacitor charges up, the current sensing threshold voltage will increase thereby causing the average LEDs current to increase.



Figure 2. Soft Start Circuit

Input Under Voltage Lockout Protection

The CS8902A has implemented input under voltage lockout to protect the sufficient V_{DD} power supply. When the V_{DD} is rising above the higher UVLO threshold voltage (V_{UVLO}), the CS8902A starts to operate. If the V_{DD} drops below the threshold voltage (V_{UVLO} – Δ V_{UVLO}), the CS8902A shutdowns.

Setting Operating Frequency

The CS8902A is capable of operating over a 25kHz and 600kHz switching frequency range. The switching frequency is programmed by connecting an external resistor between ROSC pin and ground. The corresponding oscillator frequency is as follows:

$$Fosc = \frac{25000}{Rosc + 22}$$

Where fosc unit is in kHz. Rosc unit is in k Ω . Typical values for Rosc vary from 19k Ω to 1M Ω . When driving smaller numbers of LEDs, care should be taken to ensure that ton > tLEB. The simplest way to do this is to reduce/limit the switching frequency by increasing the Rosc value. Reducing the switching frequency will also improve the efficiency.



When operating in buck mode the designer must keep in mind that the minimum input DC voltage must be maintained higher than 2 times the forward voltage drop across the LEDs. This limitation is related to the output current instability that may develop when the CS8902A operates at a duty cycle greater than 0.5. This instability reveals itself as an oscillation of the output current at a Sub-Harmonic Oscillation (SBO) of the switching frequency. The best solution is to adopt the so-called constant off-time operation as shown in Figure 3. The resistor (Rosc) is, connected to ground by default, to set operating frequency. To force the CS8902A to enter constant off-time mode Rosc is connected to the gate of the external power MOSFET. This will decrease the duty cycle from 50% by increasing the total period, toFF + toN.



Figure 3. Constant Off-Time Circuit

The oscillator period equation above now defines the CS8902A off-time, toFF. When using this mode the nominal switching frequency is chosen and from the nominal input and output voltages the off-time can be calculated :

$$Toff = (1 - \frac{VLED}{VIN})X\frac{1}{Fosc}$$

From this the timing resistor, Rosc, can be calculated as follows :

Where Toff unit is μ s. Rosc unit is in k Ω .

Inductor Selection

The non-isolated buck circuit in Figure 1 is usually selected and it has two operation modes: continuous and discontinuous conduction modes. A buck power

stage can be designed to operate in continuous mode for load current above a certain level (usually 15% to 30% of full load). Usually, the input voltage range, the output voltage and load current are defined by the power stage specification. This leaves the inductor value as the only design parameter to maintain continuous conduction mode. The minimum value of inductor to maintain continuous conduction mode can be determined by the following example.

The required minimum inductor value is determined from the desired peak-to-peak LEDs ripple current in the inductor; typically around 30% of the nominal LEDs current.

$$Lmin = \frac{(Vin - VLED)x \text{ Ton}}{0.3 \text{ x ILED}}$$

The next step is determining the total voltage drop across the LEDs string. For example, when the string consists of 8 high-brightness LEDs and each diode has a forward voltage drop of 3.0V at its nominal current; the total LEDs voltage V_{LED} is 24V.

Linear Dimming

The LEDs brightness can be dimmed either linearly (using the LD pin) or via pulse width modulation (using the PWM_D pin); or a combination of both – depending on the application. Pulling the PWM_D pin to ground will turn off the CS8902A. When disabled, the CS8902A quiescent current is typically 0.4mA. Reducing the LD voltage will reduce the LEDs current but it will not entirely turn off the external power MOSFET and hence the LEDs current – this is due to the finite blanking period. Only the PWM_D pin will turn off the external power MOSFET.

Linear dimming is accomplished by applying a 0 to 250mV analog signal to the LD pin. This overrides the default 250mV threshold level of the CS pin and reduces the output current. If an input voltage greater than 250mV is applied to the LD then the output current will not change. When the linear dimming function is not used, it is recommended that the LD pin be connected to VDD pin.

PWM Dimming

PWM dimming is achieved by applying an external PWM signal to the PWM_D pin. The LEDs current is proportional to the PWM duty cycle and the light



output can be adjusted between 0% and 100%. The PWM signal enables and disables the CS8902A modulating the LEDs current. The ultimate accuracy of the PWM dimming method is limited only by the minimum gate pulse width, which is a fraction of a percentage of the low frequency duty cycle. PWM dimming of the LEDs light can be achieved by turning on and off the converter with low frequency 50Hz to 1kHz TTL logic level signal. See Figure 4 for linear and PWM dimming input waveforms.



Figure 4. Linear and PWM Dimming Input Waveforms

With both modes of dimming it is not possible to achieve average brightness levels higher than the one set by the current sensing threshold level of the CS8902A. If a greater LEDs current is required then a smaller sensing resistor should be used.

Output Short Circuit Protection

The CS8902A can turn off external power MOSFET with minimum external sensing circuitry as soon as LED short circuit is detected. In order to achieve this, a sensing circuit, consisting of a resistor, Rst and a photo-coupler, PC817, are added in parallel with output LEDs load as shown by Figure 5. In the normal operation when LEDs are present at output, a small current (IF) flows through the resistor RsT and this current transfers the output of the photo-coupler to turn on the photo-coupler, and then Ic flows through an internal 100kΩ pull-down resistance (RPWM_D) via PWM_D pin. This on-state photo-coupler will set its emitter terminal at a voltage level close to VDD which is above VPWM_D_TH (1.3V typical) and therefore PWM_D function is disabled. As soon as these two terminals, LED+ and LED- are shorted, there will be no voltage drop across the RsT and PC817, so there is no current flowing through the photo-coupler, and PWM D pin will be pulled down to below 1.3V due to internal pull-down resistance. The external power MOSFET is turned off as soon as VPWM_D is below

 $V_{PWM_D_TH}$. For example, if PC817 forward current (IF) is 1mA, then Rst can be calculated as follows :

$$R_{ST} = \frac{VLED}{1mA}$$

Where R_{ST} unit is in k Ω .



Figure 5. Output Short Circuit Protection Circuit

Output Open Circuit Protection

The non-isolated buck LEDs driver topology provides inherent protection against an open circuit condition in the LED string due to the LEDs being connected in series with the inductor. Should the LED string become open circuit then no switching occurs and the circuit can be permanently left in this state with damage to the rest of the circuit. To avoid this problem, the designer should add RoLP resistor to LED- node.

Over Temperature Protection

The CS8902A has a built-in OTP to detect the overheated condition on the die. When the junction temperature reaches over T_{SD} (150°C typical), the CS8902A stops switching and waits for the lower threshold temperature (T_{SD} – Δ T_{SD}, 120°C typical) to start it again. The OTP can be observed in the real applications. When it reaches OTP upper threshold temperature, the LEDs blink off. It cools off below the lower threshold temperature, the LEDs blink on.

Drive Low-Cost N-channel MOSFET

While using low-cost N-channel MOSFET with small input capacitance (C_{ISS} = 180pF typical value, like Fairchild's FQP2N60C), the result is LEDs output current to decrease rapidly at higher AC line input voltage (e.g. 230V_{AC}). To improve linearity of LEDs output current, time of current sense blanking interval (t_{LEB}) must be increased. The CS8902A has a built-in this feature. Therefore, the CS8902A can drive an external low-cost N-channel MOSFET to get higher accuracy LEDs output current for higher universal AC line input voltage.

AC to DC Off-Line LEDs Driver

The CS8902A is a cost-effective off-line buck LEDs driven controller specifically designed for driving LED strings. It is suitable for being used with either rectified AC line voltage or any DC voltage between 9V to 500V. See Figure 1 for Typical Application Circuit without PFC (Power Factor Correction).

Buck design equations :

$$D = \frac{\text{VLED}}{\text{Vin}}$$
$$Ton = \frac{\text{D}}{\text{Fosc}}$$
$$Lmin = \frac{(\text{Vin} - \text{VLED}) \times \text{Ton}}{0.3 \times \text{ILED}}$$
$$Rcs = \frac{0.25}{1.15 \times \text{ILED}}$$

Design Example

For an AC line voltage of 230V_{AC} the nominal rectified DC input voltage Vin = 230VAC x $\sqrt{2}$ = 325VFrom this and the LEDs chain voltage the duty cycle can be determined :

$$D = \frac{\text{VLED}}{\text{Vin}}$$
$$= \frac{24}{325}$$
$$= 0.074$$

From the switching frequency, for example fosc = 47 kHz, the required on-time of the external power MOSFET can be calculated :

$$Ton = \frac{D}{Fosc}$$
$$= \frac{0.074}{47K}$$
$$= 1.57us$$

The minimum value of the inductor for LEDs current of 350mA is determined as follows :

$$Lmin = \frac{(Vin - VLED)x \text{ Ton}}{0.3 \text{ x ILED}}$$
$$= \frac{(325 - 24)x 1.57us}{0.3 \text{ x } 350mA}$$
$$= 4.5mH$$

Input Bulk Capacitor

For off-line lamps an input bulk capacitor is required to ensure that the rectified AC voltage is held above twice the LED string voltage throughout the AC line cycle. The value can be calculated from :

$$CIN \ge \frac{PIN \ x \ (1 - DCH)}{\sqrt{2} \ x \ VAC_\min x \ 2FL \ x \ \Delta VDC_max}$$

Where

DCH: C_{IN} capacity charge work period, generally about 0.20 ~ 0.25,

FL : input line frequency (47Hz ~ 63Hz) for full AC line voltage range (85V_{AC} ~ 305V_{AC}),

 Δ VDC_max : should be set 10% ~ 15% of ($\sqrt{2} x VAC_min$)

If the capacitor has a 15% voltage ripple then a simplified formula for the minimum value of the bulk input capacitor approximates to :

$$CIN_min = \frac{ILED \times VLED \times 0.06}{VIN^2}$$
$$= 4.77 \text{ uF}$$

For this example, the voltage rating of the capacitor should be more than V_{IN} with some safety margin factored in. An electrolytic capacitor with a 400V, 6.8µF rating would be adequate.

Note that electrolytic bulk capacitors contain parasitic elements that cause their performance to be less than ideal. One important parasitic is the capacitor's Equivalent Series Resistance (ESR), which causes internal heating as the ripple current flows into and out of the capacitor. In order to select a proper capacitor, the designer should consider capacitors that are specifically designed to endure the ripple current at the maximum temperature, and that have an ESR that is guaranteed within a specific frequency range (usually provided by manufacturers in the 120Hz to 100kHz range). The Effective Series Inductance (ESL) is another parasitic that limits the effectiveness of the electrolytic capacitor at high frequencies.

The combination of the variation of ESR over temperature and a high ESL may require adding a parallel film or tantalum capacitor (Cc) to absorb the high-frequency ripple component. This keeps the combined ESR within the required limit over the full design temperature range.

Power Factor Collection

If power factor improvement is required then for the input power less than 25W, a simple passive power factor correction circuit can be added to the CS8902A typical application circuit. Figure 6 show that passive PFC circuitry (3 current steering diodes and 2 identical capacitors) does not significantly affect the rest of the circuit. Simple passive PFC circuit improves the line current harmonic distortion and achieves a power factor greater than 0.85.

Each of these identical capacitors should be rated for half of the maximum input DC voltage and have twice as much capacitance as the calculated CIN_MIN of the buck converter circuit without passive PFC (see above section on input bulk capacitor calculation).

DC-DC Buck LEDs Driver

The design procedure for an AC input buck LEDs driver outlined in the previous chapters equally applies DC input LEDs drivers. When driving long LEDs chains care should be taken not to induce SBO – maximum LED chain voltage should be less half of VIN. So either maximum duty cycle should be kept below 50% or use of constant offtime operation removes this issue.

DC-DC Boost LEDs Driver

Due to the topology of the CS8902A LEDs driven controller it is capable of being used in boost configurations – at reduced accuracy. The current accuracy can be improved by measuring the LEDs current with an Op Amp and use the Op Amp's output to drive the LD pin.

A boost LEDs driver is used when the forward voltage drop of the LED string is higher than the input supply voltage. For example, the boost topology (see Figure 8) can be appropriate when input voltage is supplied by a 48V power supply and the LED string consists of twenty high-brightness LEDs, as the case may be for a street light.

In a boost converter, when the external power MOSFET is on the energy is stored in the inductor which is then delivered to the output when the external power MOSFET switches off. If the energy stored in the inductor is not fully depleted by the next switching cycle (continuous conduction mode) the DC conversion between input and output voltage is given by :

$$\frac{VLED}{VIN} = \frac{1}{1-D}$$
$$D = \frac{VLED - VIN}{VLED}$$

From the switching frequency, Fosc, the on-time of the external power MOSFET can be calculated :

$$Ton = \frac{D}{Fosc}$$

From this the required inductor value can be determined by :

$$L \ge \frac{VIN \ x \ Ton}{0.3 \ x \ ILED}$$

The boost topology LEDs driver requires an output capacitor to deliver current to the LED string during the time that the external power MOSFET is on. In boost LEDs driver topologies if the LEDs should become open circuit damage may occur to the power switch and so some form of detection should be present to provide over-voltage detection/protection.





Figure 6. Typical Application Circuit with Passive PFC



Figure 7. DC-DC Buck LEDs Driver



Figure 8. DC-DC Boost LEDs Driver



Package Outline Dimension

(1). SOP-8 : 8-Lead SOP Plastic Package



Symphol	Dimensions i	n millimeters	Dimensions in inches		
Symbol	Min	Мах	Min	Мах	
Α		1.750		0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.250		0.049		
В	0.310	0.510	0.012	0.020	
С	0.170	0.250	0.007	0.010	
D	4.900	BSC	0.193 BSC		
E	6.000	BSC	0.236 BSC		
E1	3.900 BSC		0.154 BSC		
F	1.270 BSC		0.050 BSC		
н	0.250	0.500	0.010	0.020	
L	0.400	1.270	0.016	0.050	
L1	1.040	REF	0.041 REF		
L2	0.250	BSC	0.010 BSC		
θ°	0	8	0	8	



(2). PSOP-8 : 8-Lead SOP Exposed Pad (Heat Sink) Plastic Package



Symbol	Dimensions i	in millimeters	Dimensions in inches		
	Min	Мах	Min	Мах	
Α		1.750		0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.250		0.049		
В	0.310	0.510	0.012	0.020	
С	0.170	0.250	0.007	0.010	
D	4.900	BSC	0.193 BSC		
E	6.000	BSC	0.236 BSC		
E1	3.900	BSC	0.154 BSC		
F	1.270	BSC	0.050 BSC		
н	0.250	0.500	0.010	0.020	
L	0.400	1.270	0.016	0.050	
L1	1.040) REF	0.041 REF		
L2	0.250	BSC	0.010 BSC		
θ°	0	8	0	8	
X	2.186	2.386	0.086	0.094	
Y	2.186	2.386	0.086	0.094	